CMOS Digital Integrated Circuits Silicon Monolithic

74HC374D

1. Functional Description

Octal D-Type Flip Flop with 3-State Outputs

2. General

The 74HC374D is a high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

These 8-bit D-type flip-flops are controlled by a clock input (CK) and an output enable input (OE).

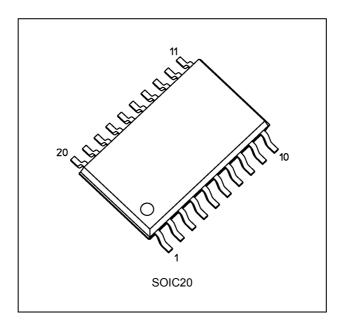
When the input is high, the eight outputs are in a high impedance state.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

3. Features

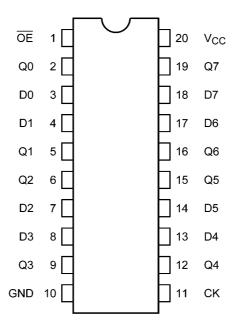
- (1) High speed: $f_{MAX} = 90 \text{ MHz}$ (typ.) at $V_{CC} = 6.0 \text{ V}$
- (2) Low power dissipation: $I_{CC} = 4.0 \mu A \text{ (max)}$ at $T_a = 25 \text{ °C}$
- (3) Balanced propagation delays: t_{PLH} ≈ t_{PHL}
- (4) Wide operating voltage range: $V_{CC(opr)} = 2.0 \text{ V}$ to 6.0 V

4. Packaging

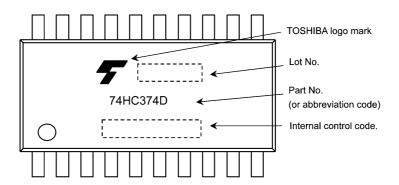




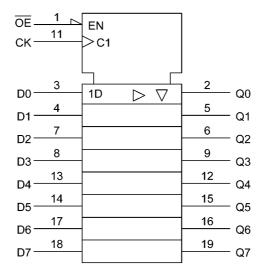
5. Pin Assignment



6. Marking



7. IEC Logic Symbol



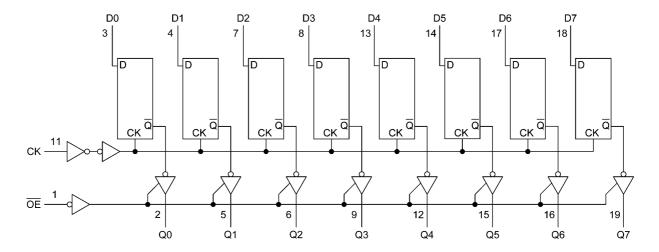


8. Truth Table

	Inputs	Output				
ŌĒ	СК	D	Output			
Н	Х	Х	Z			
L	□	Х	Qn			
L		L	L			
L		Н	Н			

X: Don't careZ: High impedanceQn: No change

9. System Diagram





10. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to V _{CC} + 0.5	V
Output voltage	V _{OUT}		-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}		±20	mA
Output diode current	I _{OK}		±20	mA
Output current	I _{OUT}		±35	mA
V _{CC} /ground current	I _{CC}		±75	mA
Power dissipation	P _D	(Note 1)	500	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: PD derates linearly with -8 mW/°C above 85 °C

11. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V _{CC}	_	2.0 to 6.0	V
Input voltage	V _{IN}		0 to V _{CC}	V
Output voltage	V _{OUT}		0 to V _{CC}	V
Operating temperature	T _{opr}		-40 to 125	°C
Input rise and fall times	t _r ,t _f	_	0 to 50	μS

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.



12. Electrical Characteristics

12.1. DC Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}	_	_		1.50	_	_	V
				4.5	3.15	_	_	
				6.0	4.20	_	_	
Low-level input voltage	V _{IL}	_		2.0		_	0.50	V
				4.5			1.35	
				6.0		_	1.80	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -20 μA	2.0	1.9	2.0	_	V
				4.5	4.4	4.5	_	
				6.0	5.9	6.0	_	
			I _{OH} = -6 mA	4.5	4.18	4.31	_	
			I _{OH} = -7.8 mA	6.0	5.68	5.80	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 20 μA	2.0	_	0.0	0.1	V
				4.5	_	0.0	0.1	
				6.0	_	0.0	0.1	
			I _{OL} = 6 mA	4.5	_	0.17	0.26	
			I _{OL} = 7.8 mA	6.0		0.18	0.26	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	_	_	±0.5	μА
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND		6.0		_	±0.1	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND I _O = 0 A		6.0	_	_	4.0	μА

12.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition	1	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	V
				4.5	3.15	_	
				6.0	4.20	_	
Low-level input voltage	V _{IL}	_		2.0	ı	0.50	\ \
				4.5	ı	1.35	
				6.0		1.80	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OH} = -20 μA	2.0	1.9	_	\ \
				4.5	4.4	_	
				6.0	5.9	_	
			I _{OH} = -6 mA	4.5	4.13	_]
			I _{OH} = -7.8 mA	6.0	5.63	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 20 μA	2.0	_	0.1	V
				4.5	_	0.1]
				6.0	_	0.1]
			I _{OL} = 6 mA	4.5	_	0.33	
			I _{OL} = 7.8 mA	6.0	_	0.33]
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	_	±5.0	μА
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND		6.0		±1.0	μА
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND $I_O = 0$ A		6.0	_	40.0	μА



12.3. DC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	V
				4.5	3.15	_	
				6.0	4.20	_	
Low-level input voltage	V _{IL}	_		2.0	_	0.50	V
				4.5		1.35	
				6.0	_	1.80	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -20 μA	2.0	1.9	_	V
				4.5	4.4	_	
				6.0	5.9	_	
			I _{OH} = -6 mA	4.5	3.7	_	
			I _{OH} = -7.8 mA	6.0	5.2	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 20 μA	2.0	_	0.1	V
				4.5	_	0.1	
				6.0	_	0.1	
			I _{OL} = 6 mA	4.5		0.4	
			I _{OL} = 7.8 mA	6.0	_	0.4	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	_	±10.0	μА
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND		6.0	_	±1.0	μА
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND $I_O = 0$ A		6.0	_	160.0	μА



12.4. Timing Requirements (Unless otherwise specified, $T_a = 25$ °C, Input: $t_f = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Minimum pulse width	$t_{w(L)}, t_{w(H)}$	_	2.0	_	75	ns
(CK)			4.5	_	15	
			6.0	_	13	
Minimum setup time	t _S	_	2.0	_	75	ns
(Dn)			4.5	_	15	
			6.0	_	13	
Minimum hold time	t _h	_	2.0	_	0	ns
(Dn)			4.5	_	0	
			6.0	_	0	
Clock frequency	f	_	2.0	_	6	MHz
			4.5	_	31	
			6.0	_	36	

12.5. Timing Requirements (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Limit	Unit
Minimum pulse width	$t_{w(L)}, t_{w(H)}$	_	2.0	95	ns
(CK)			4.5	19	
			6.0	16	
Minimum setup time	t _S	_	2.0	95	ns
(Dn)			4.5	19	
			6.0	16	
Minimum hold time	t _h	_	2.0	0	ns
(Dn)		İ	4.5	0	
			6.0	0	
Clock frequency	f	_	2.0	5	MHz
			4.5	25	
			6.0	29	

12.6. Timing Requirements (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_f = t_f = 6 ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Limit	Unit
Minimum pulse width	$t_{w(L)},t_{w(H)}$	_	2.0	120	ns
(CK)			4.5	24	
			6.0	20	
Minimum setup time	t _S	_	2.0	120	ns
(Dn)			4.5	24]
			6.0	20	
Minimum hold time	t _h	_	2.0	0	ns
(Dn)			4.5	0	
			6.0	0	
Clock frequency	f	_	2.0	4	MHz
			4.5	20	
			6.0	24	



12.7. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Note	Test Condition	C _L (pF)	V _{CC} (V)	Min	Тур.	Max	Unit
Output transition time	t _{TLH} ,t _{THL}		_	50	2.0	_	20	60	ns
					4.5	_	6	12	
					6.0	_	5	10	
Propagation delay time	t _{PLH} ,t _{PHL}		_	50	2.0	_	45	140	ns
(CK-Q)					4.5	_	15	28	
					6.0	_	13	24	
				150	2.0	_	60	190	
					4.5	_	20	38	
					6.0	_	17	32	
Output enable time	t _{PZL} ,t _{PZH}		$R_L = 1 k\Omega$	50	2.0	_	39	135	ns
					4.5	_	13	27	
					6.0	_	11	23	
				150	2.0	_	54	185	
					4.5	_	18	37	
					6.0	_	15	31	
Output disable time	t_{PLZ}, t_{PHZ}		$R_L = 1 k\Omega$	50	2.0	_	30	135	ns
					4.5	_	13	27	
					6.0	_	12	23	
Maximum clock frequency	f _{MAX}		_	50	2.0	6	18	_	MHz
					4.5	31	75	_	
					6.0	36	90	_	
Input capacitance	C _{IN}		_				3		pF
Output capacitance	C _{OUT}		_			1	4		pF
Power dissipation capacitance	C _{PD}	(Note 1)	_				11	_	pF

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$ (per latch)

And the total C_{PD} when n pcs of latch operate can be gained by the following equation.

 C_{PD} (total) = 22 + 16 × n



12.8. AC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C, Input: t_f = t_f = 6 ns)

Characteristics	Symbol	Test Condition	C _L (pF)	V _{CC} (V)	Min	Max	Unit	
Output transition time	t _{TLH} ,t _{THL}	_	50	2.0	_	75	ns	
				4.5	_	15		
				6.0	_	13		
Propagation delay time	t _{PLH} ,t _{PHL}	_	50	2.0	_	175	ns	
(CK-Q)				4.5	_	35		
				6.0	_	30		
			150	2.0	_	240		
				4.5	_	48		
				6.0	_	41		
Output enable time	t _{PZL} ,t _{PZH}	$R_L = 1 k\Omega$	50	2.0	_	170	ns	
				4.5	_	34		
				6.0	_	29		
			150	2.0	_	230		
				4.5	_	46		
				6.0	_	39		
Output disable time	t_{PLZ}, t_{PHZ}	$R_L = 1 k\Omega$	50	2.0	_	170	ns	
					4.5	_	34	
				6.0	_	29		
Maximum clock frequency	f _{MAX}	_	50	2.0	5	_	MHz	
				4.5	25	_		
				6.0	29	_		

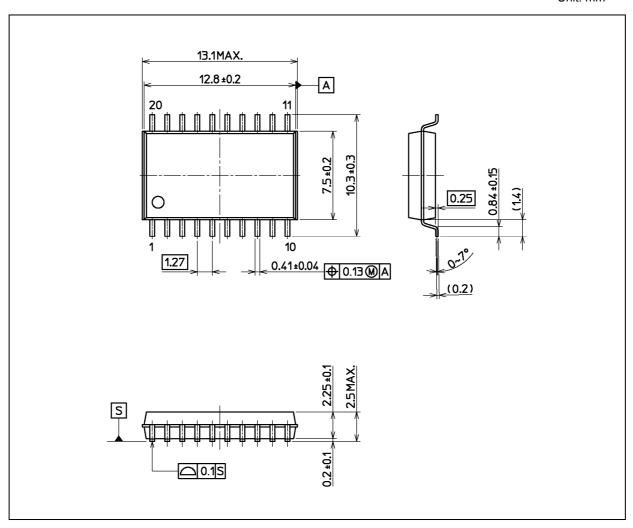
12.9. AC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_r = t_f = 6 ns)

Characteristics	Symbol	Test Condition	C _L (pF)	V _{CC} (V)	Min	Max	Unit
Output transition time	t _{TLH} ,t _{THL}	_	50	2.0		90	ns
				4.5		18	
				6.0		15	
Propagation delay time	t _{PLH} ,t _{PHL}	_	50	2.0		250	ns
(CK-Q)				4.5	_	50	
				6.0		43	
			150	2.0		285	
				4.5		57	
				6.0		48	
Output enable time	t _{PZL} ,t _{PZH}	$R_L = 1 k\Omega$	50	2.0		205	ns
				4.5		41	
				6.0	_	35	
			150	2.0		280	
				4.5		56	
				6.0	_	48	
Output disable time	t_{PLZ}, t_{PHZ}	$R_L = 1 k\Omega$	50	2.0	_	205	ns
				4.5	_	41	
				6.0	_	35	
Maximum clock frequency	f _{MAX}	_	50	2.0	4	_	MHz
				4.5	20	_]
				6.0	24		



Package Dimensions

Unit: mm



Weight: 0.51 g (typ.)

	Package Name(s)
Nickname: SOIC20	



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